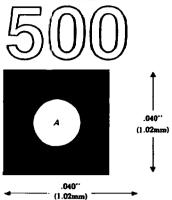
Solitron

MEDIUM TO HIGH VOLTAGE

CHIP NUMBER



Anode:

.020" (0.51mm) dia.

PN EPITAXIAL PLANAR POWER DIODE

CONTACT METALLIZATION

Anode: > 30.000 Å Aluminum

Cathode: Gold

(Polished silicon or "Chrome Nickel Silver" also available)

Also available on:

MOLY PEDESTAL

Size:

.140" Dicmeter (3.56mm)

Thickness:

.010" (0.25mm)

ASSEMBLY RECOMMENDATIONS

It is advisable that:

- a) the chip be eutectically mounted with gold silicon preform 98/2%.
- b) 8 mil (0.203mm) aluminum wire be ultrasonically attached to the anode contact.

TYPICAL ELECTRICAL CHARACTERISTICS AT 25°C

The following typical electrical characteristics apply for a completely finished component employing the chip number 500 in a DO-4 or equivalent case:

Minimum VR @ 10 μA	I _R @ 80% V _R	V _F @	IF	IF Surge	$\begin{array}{c} \text{Maximum } t_{rr} @ I_F = I_R = 1.0 \text{A} \\ I_{REC} = 0.25 \text{A} \end{array}$
> 5 0V	<5μ Ā	1. 2V	1.5 A	>100A	200 ns
>100V	<5μΑ	1.2 V	1.5A	>100A	200 ns
>20 0V	<5μ Ā	1.2 V	1.5A	>100A	200 ns
>30 0V	<5μΑ	1.2 V	1.5A	>100Å	200 ns
>40 0V	<5μΑ	1.2 V	1.5 A	>100A	450 ns
>50 0V	<5μ Ä	1.2V	1.5 A	>100A	450 ns
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TYPICAL DEVICE TYPES:

1N5614, 1N5615, 1N5616

IF surge ≥ 60A.